NSN 5961-01-330-7764

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-330-7764 **Inclosure Material:** Plastic **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.085 inches and 0.130 inches **Mounting Method:** Terminal **Terminal Circle Diameter:** Between 0.018 inches and 0.022 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1.50 forward voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset and 50.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 0.4 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Electrostatic sensitive device; hardness critical item **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: